

# RJK2511DPK

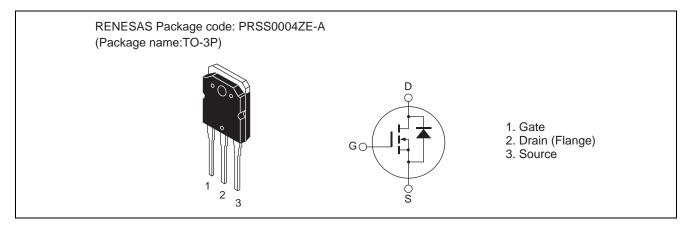
# Silicon N Channel MOS FET High Speed Power Switching

REJ03G1486-0500 Rev.5.00 Jun 30, 2010

#### **Features**

- Low on-resistance
- Low leakage current
- High speed switching

#### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	250	V
Gate to source voltage	V <sub>GSS</sub>	±30	V
Drain current	I <sub>D</sub>	65	Α
Drain peak current	I <sub>D (pulse)</sub> Note1	200	Α
Body-drain diode reverse drain current	I <sub>DR</sub>	65	Α
Body-drain diode reverse drain peak current	I <sub>DR (pulse)</sub> Note1	200	Α
Avalanche current	I <sub>AP</sub> Note3	22	Α
Avalanche energy	E <sub>AR</sub> Note3	30.2	mJ
Channel dissipation	Pch Note2	200	W
Channel to case thermal impedance	θch-c	0.625	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

- 2. Value at Tc = 25°C
- 3. STch =  $25^{\circ}$ C, Tch  $\leq 150^{\circ}$ C

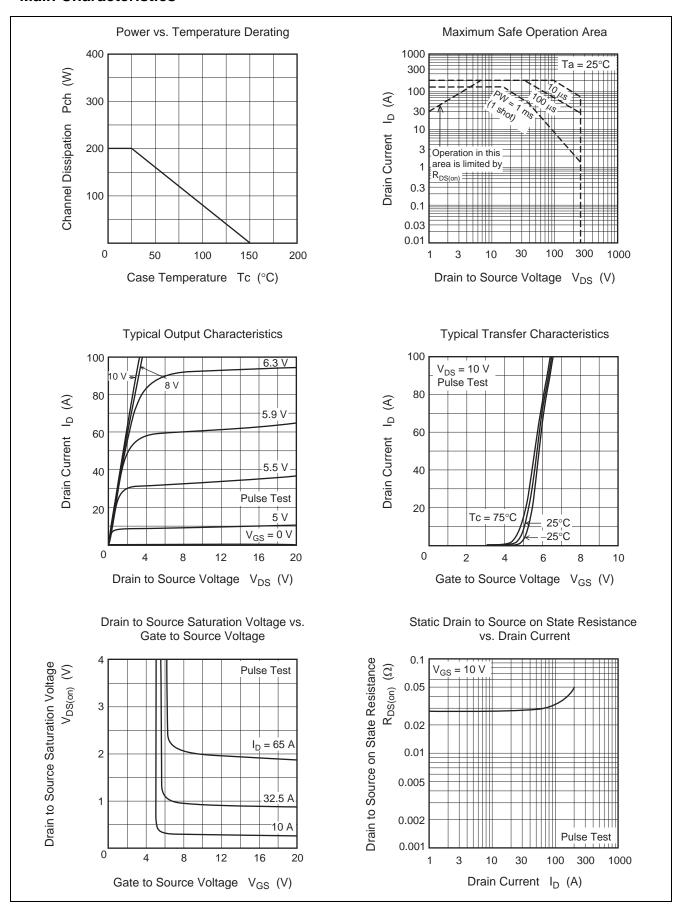
# **Electrical Characteristics**

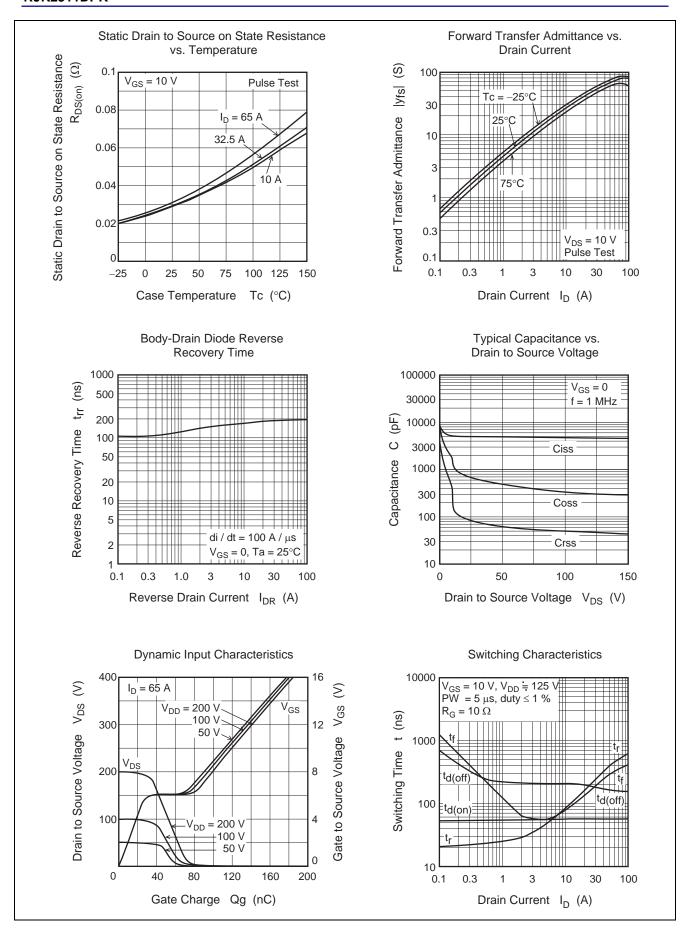
 $(Ta = 25^{\circ}C)$ 

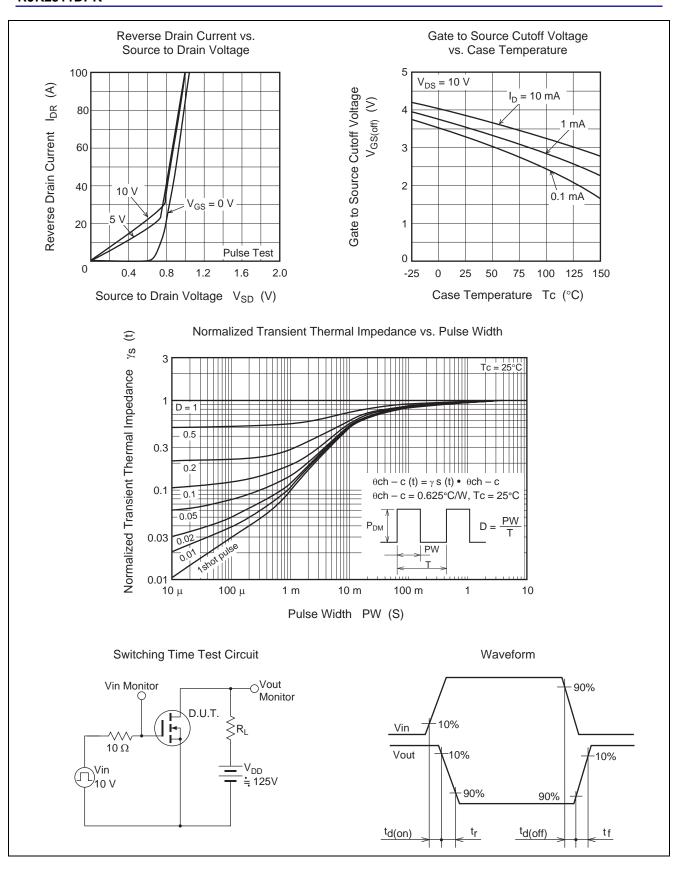
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	250	_		V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 250 \text{ V}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Forward transfer admittance	yfs	30	51	_	S	$I_D = 32.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Static drain to source on state	R <sub>DS(on)</sub>	_	0.028	0.034	Ω	$I_D = 32.5 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance						
Input capacitance	Ciss	_	4900		pF	$V_{DS} = 25 \text{ V}$
Output capacitance	Coss	_	690	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	85	_	pF	f = 1 MHz
Turn-on delay time	t <sub>d(on)</sub>	_	52	_	ns	I <sub>D</sub> = 32.5 A
Rise time	t <sub>r</sub>	_	200	_	ns	$V_{GS} = 10 \text{ V}$
Turn-off delay time	t <sub>d(off)</sub>	_	160	_	ns	$R_L = 3.9 \Omega$
Fall time	t <sub>f</sub>	_	150	_	ns	$Rg = 10 \Omega$
Total gate charge	Qg	_	120	_	nC	V <sub>DD</sub> = 200 V
Gate to source charge	Qgs	_	28	_	nC	V <sub>GS</sub> = 10 V I <sub>D</sub> = 65 A
Gate to drain charge	Qgd	_	51	_	nC	
Body-drain diode forward voltage	$V_{DF}$	_	0.93	1.50	V	$I_F = 65 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	200	_	ns	$I_F = 65 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery	Q <sub>rr</sub>	_	1.5	_	μС	$di_F/dt = 100 A/\mu s$
charge						

Notes: 4. Pulse test

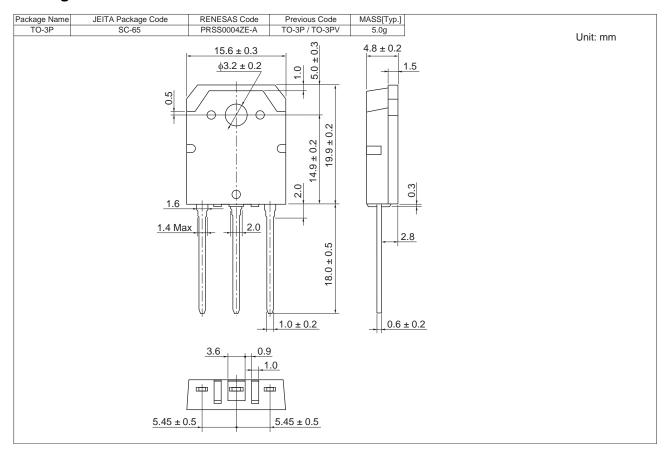
#### **Main Characteristics**







# **Package Dimensions**



# **Ordering Information**

Part No.	Quantity	Shipping Container
RJK2511DPK-00-T0	360 pcs	Box (Tube)

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